

Incipient Wetness Impregnation



Supporting metals/metal oxides on TiO₂ surface decreases the band gap via a synergistic effect with the Valence (VB) and Conduction (CB) band positions of the TiO₂ and the Fermi level of metal and or the VB/CB position of metal oxide

Annealing



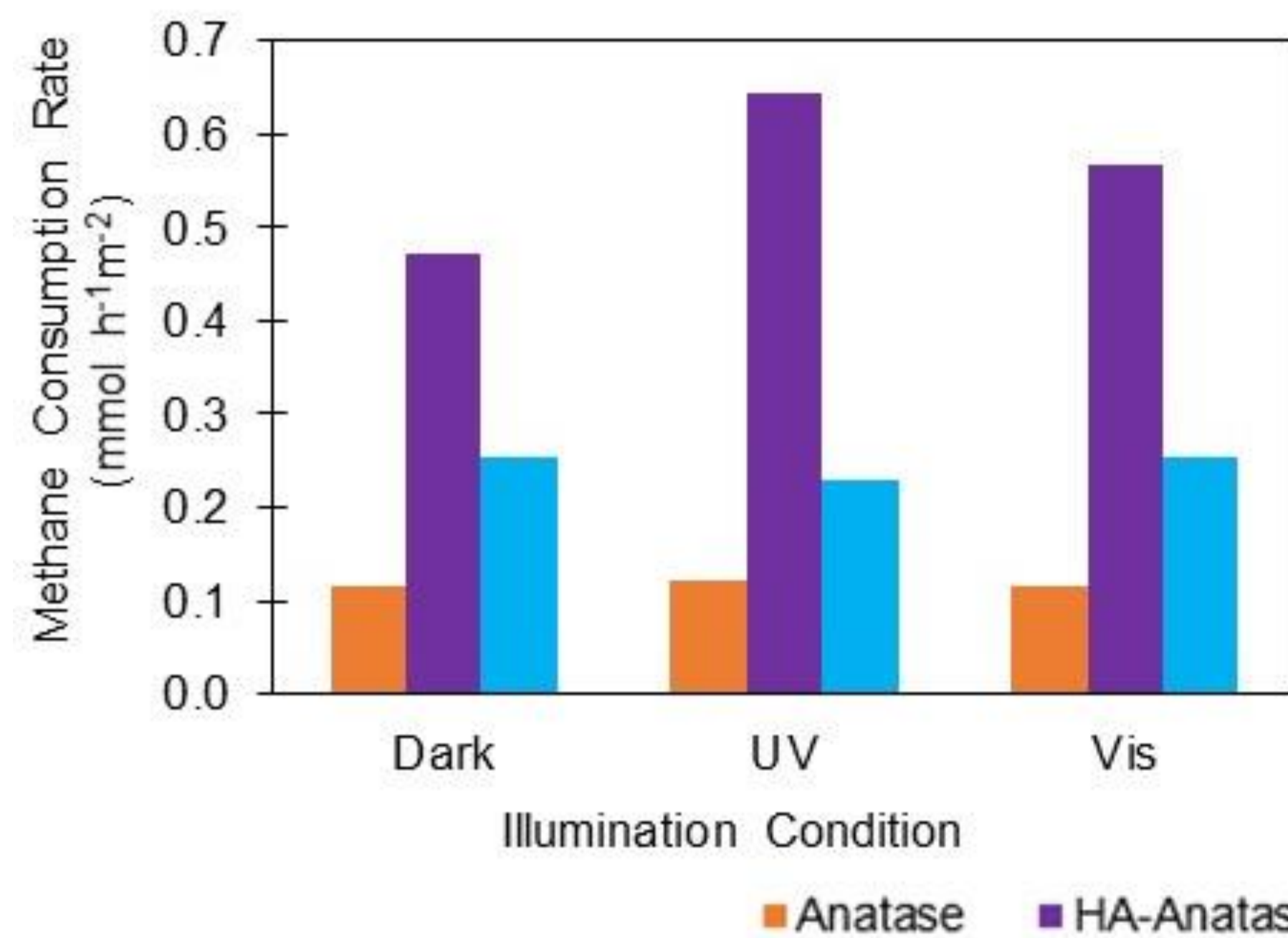
High Temperature High Pressure (HPHT) Annealing produces Ti³⁺ Centers, Oxygen vacancies, and defects that effect the reactivity and BGE of metal oxide semiconductor catalysts

Flame Synthesis Carbon Doping

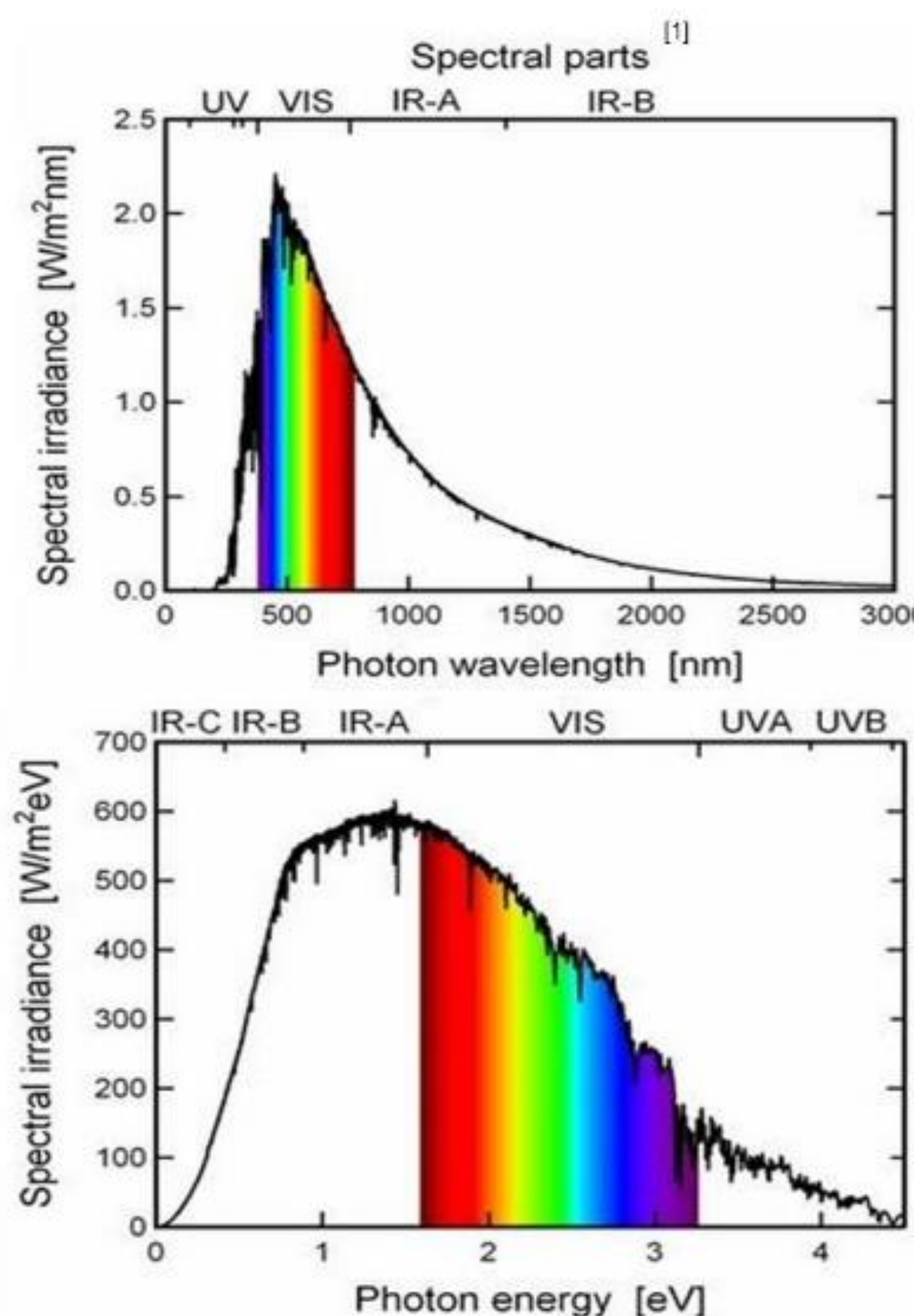
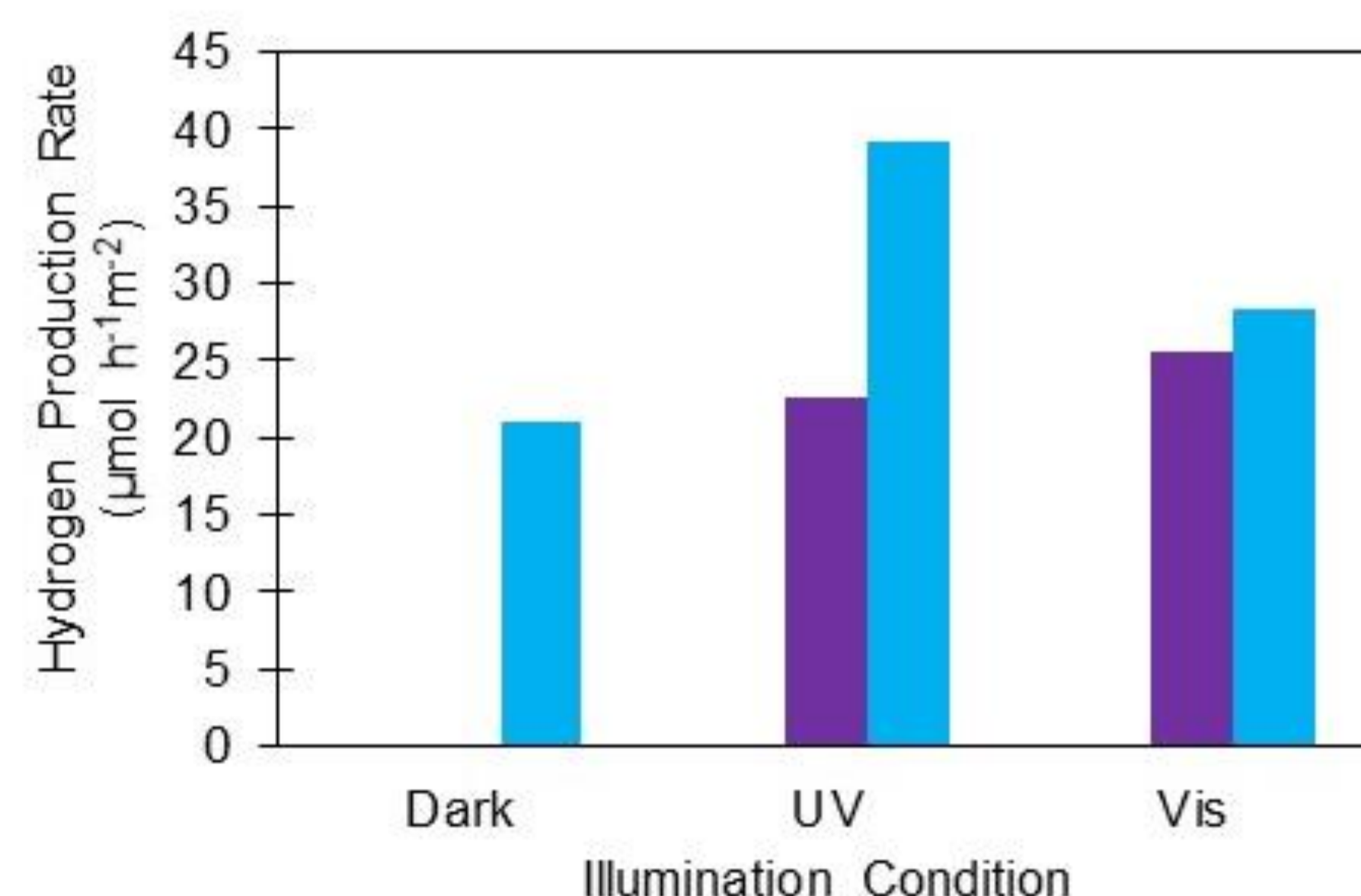


Carbon doping via low pressure flame synthesis stabilizes defects in the crystal lattice which is hypothesized to increase the photocatalytic activity of metal oxide semiconductors

Methane Consumption Rate at 700 °C



Hydrogen Production Rate at 700 °C



[1] C. Gueymard, Solar Energy (2004) 423.

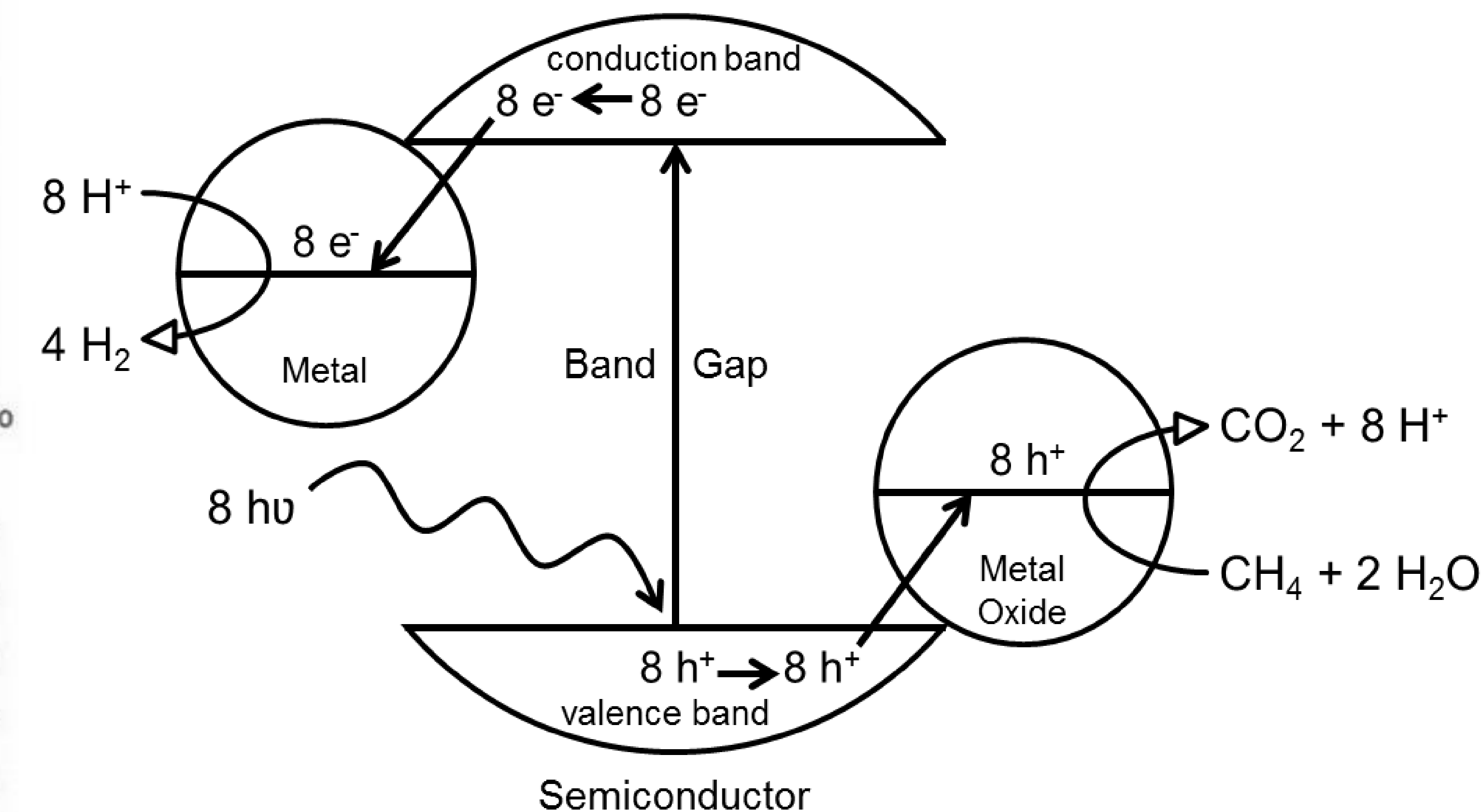
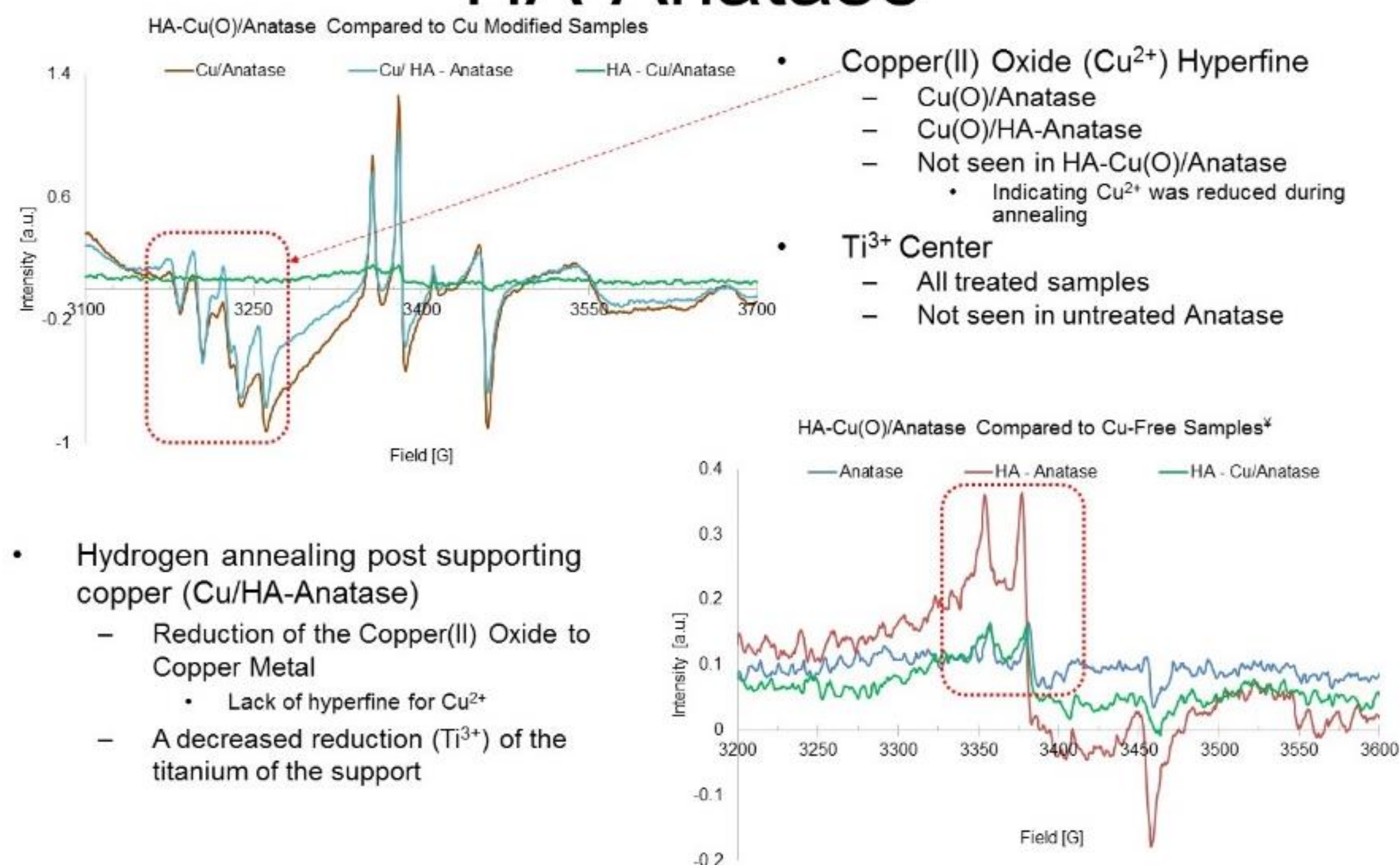


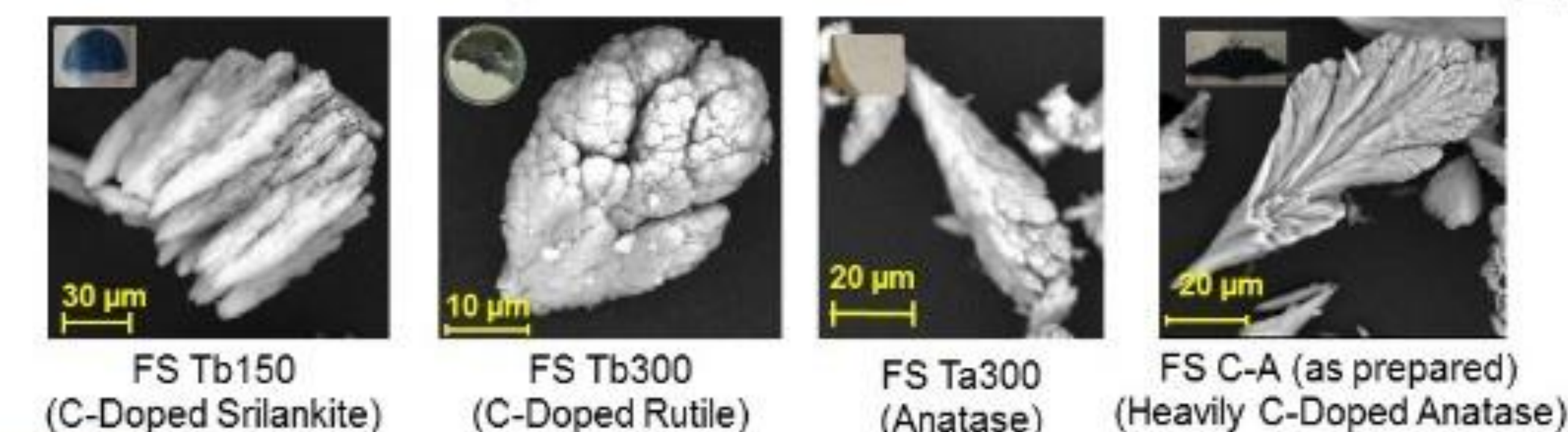
Figure: MSR on a semiconductor photocatalyst with supported metal and metal oxide nanoparticles.

EPR Analysis of Copper Supported on HA-Anatase



Low Pressure Flame Synthesized TiO₂

Low Pressure Flame Spray Pyrolysis was a synthesis method to synthesize various polymorphs of carbon-doped TiO₂ from Titanium isopropoxide precursor.



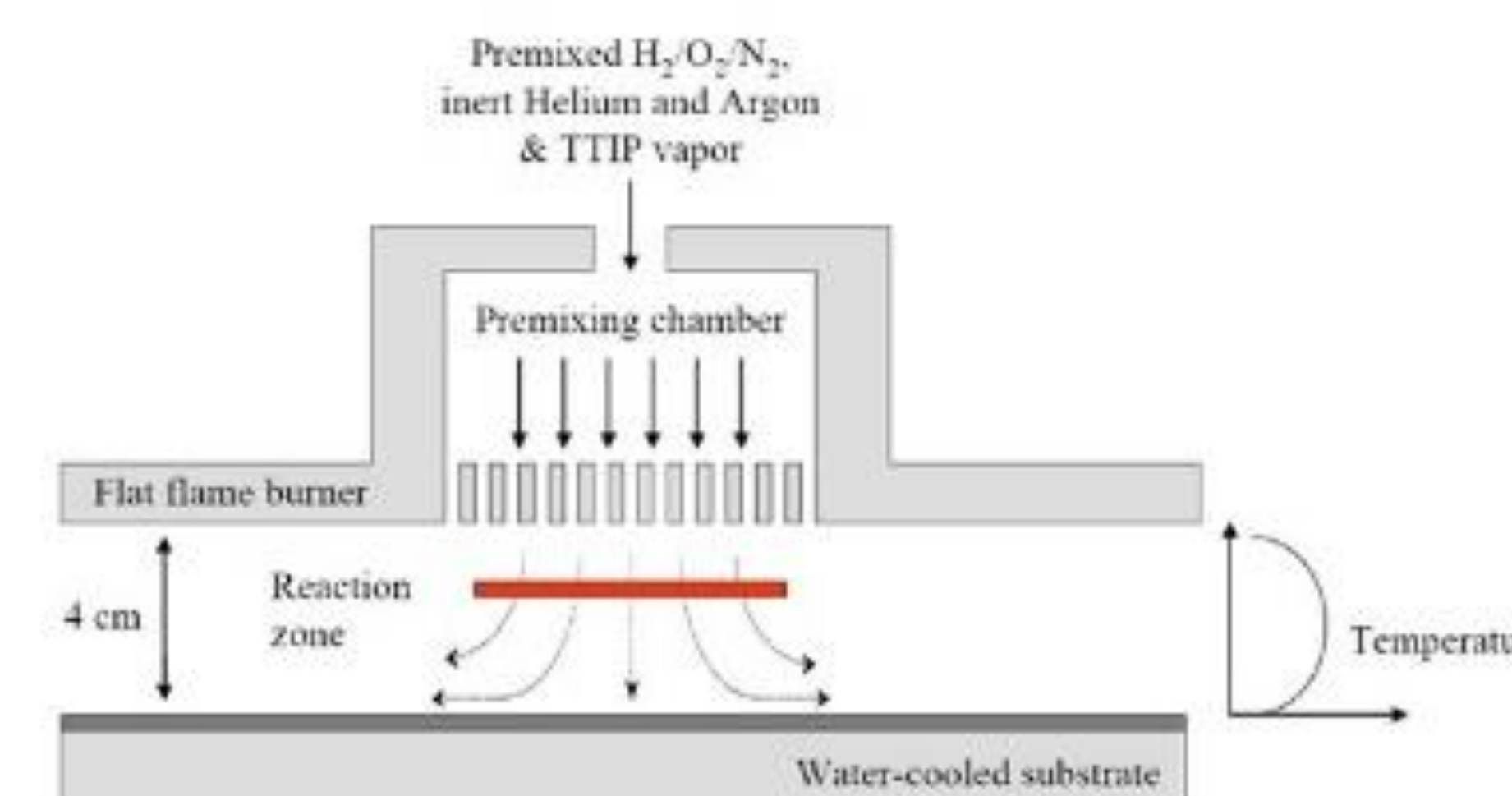
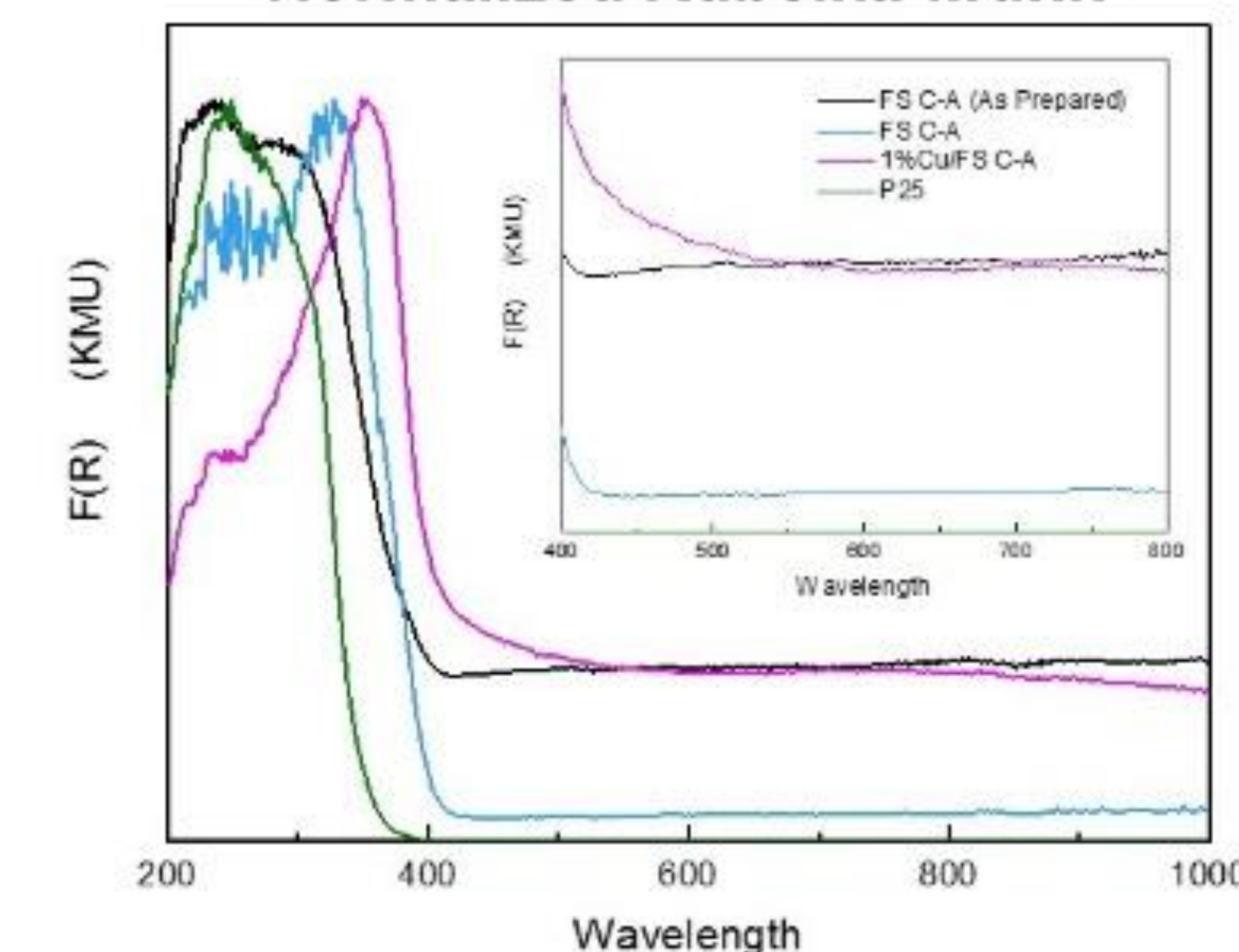
Pre-mixed gases fed into the chamber, maintained at a 20 torr during the synthesis.

Sample	Tauc ^{1/2} BGE [eV]	dR _∞ /dt BGE [eV]
FS Tb150	3.35	3.42, 3.63
FS Tb300	3.46	3.34, 3.04
FS Ta300	3.27	3.29, 3.57
FS C-A (as prepared)	2.75	3.27*
FS C-A (Calcined)	2.95	3.07, 3.17
1%Cu(O)/FSCA	2.78	3.19, 2.83

* Low intensity of derivative peak

1%Cu/FS C-A has a small BGE, 2.75 eV, and the absorbance of in the visible spectrum was greater than pure TiO₂ (P25) indicating that 1%Cu/FS C-A could potentially be a good visible-light-active photocatalyst.

Normalized Kubelka-Munk



Synthesis performed in Laboratory of Dr. Stephen Tse, Mechanical and Aerospace Engineering Department at Rutgers. Training and first set of samples provided by Hadi Halim.